

RJP60F5DPK

600V - 40A - IGBT
High Speed Power Switching

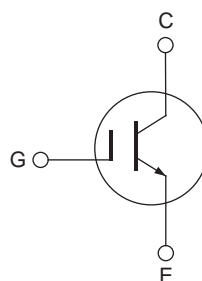
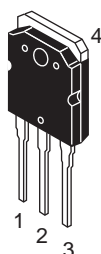
R07DS0757EJ0100
Rev.1.00
May 31, 2012

Features

- Low collector to emitter saturation voltage
 $V_{CE(sat)} = 1.37 \text{ V typ. (} I_C = 40 \text{ A, } V_{GE} = 15 \text{ V, } T_a = 25^\circ\text{C)}$
- High speed switching
 $t_f = 85 \text{ ns typ. (at } I_C = 30 \text{ A, } V_{CE} = 400 \text{ V, } V_{GE} = 15 \text{ V, } R_g = 5 \Omega, T_a = 25^\circ\text{C, inductive load)}$

Outline

RENESAS Package code: PRSS0004ZE-A
(Package name: TO-3P)



1. Gate
2. Collector
3. Emitter
4. Collector

Absolute Maximum Ratings

($T_c = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit	
Collector to emitter voltage	V_{CES}	600	V	
Gate to emitter voltage	V_{GES}	± 30	V	
Collector current	$T_c = 25^\circ\text{C}$	I_C	80	A
	$T_c = 100^\circ\text{C}$	I_C	40	A
Collector peak current	$i_{c(peak)}$ ^{Note1}	160	A	
Collector dissipation	P_C	260.4	W	
Junction to case thermal impedance	θ_{j-c}	0.48	$^\circ\text{C/W}$	
Junction temperature	T_j	150	$^\circ\text{C}$	
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$	

Notes: 1. Pulse width limited by safe operating area.

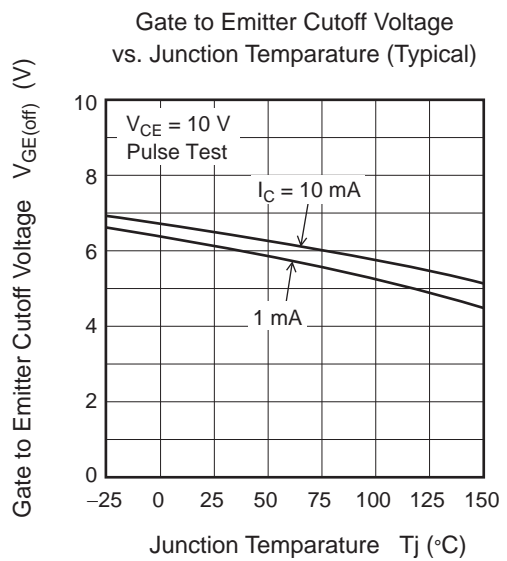
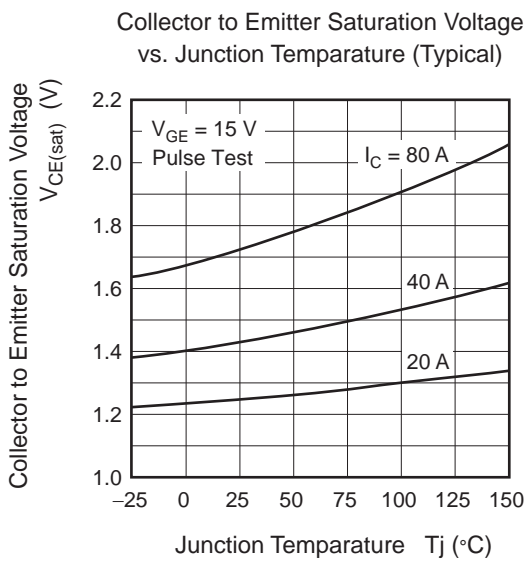
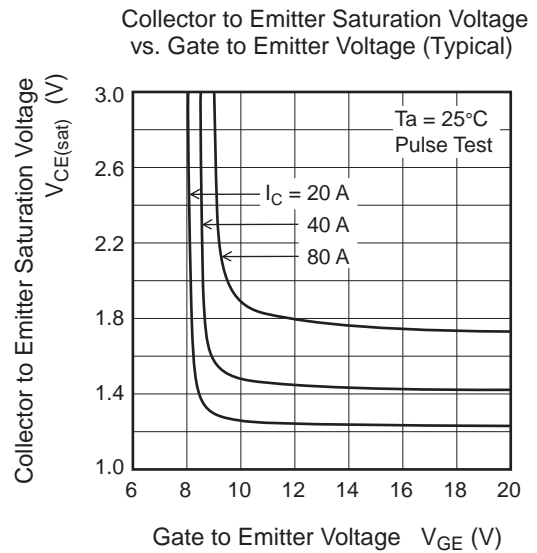
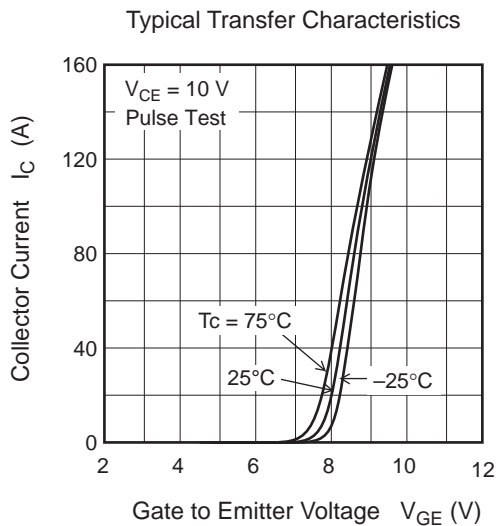
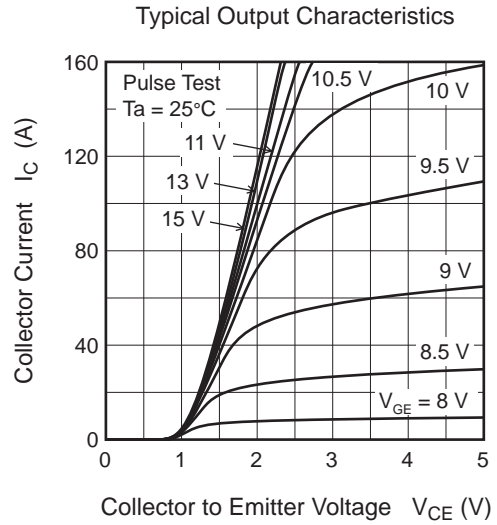
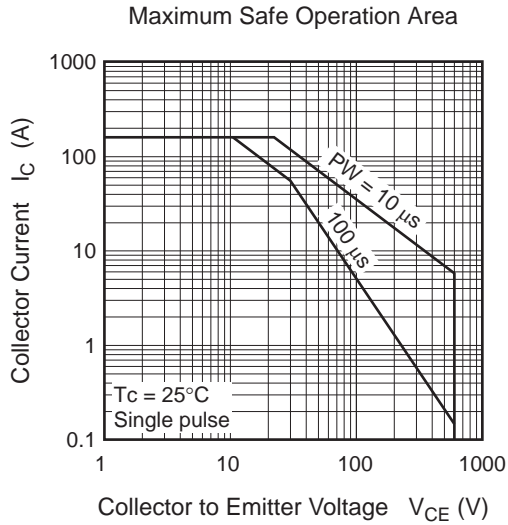
Electrical Characteristics

(T_j = 25°C)

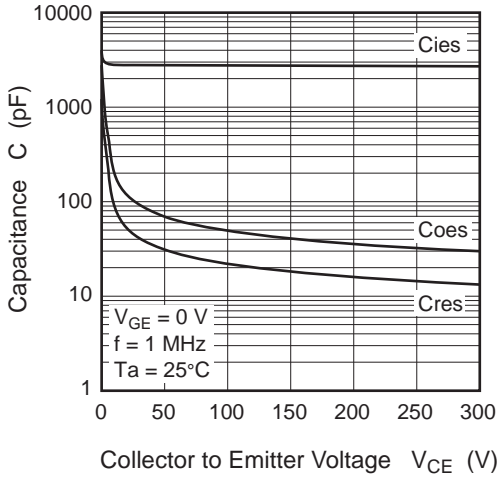
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero gate voltage collector current	I _{CES}	—	—	100	μA	V _{CE} = 600V, V _{GE} = 0
Gate to emitter leak current	I _{GES}	—	—	±1	μA	V _{GE} = ±30 V, V _{CE} = 0
Gate to emitter cutoff voltage	V _{GE(off)}	4	—	8	V	V _{CE} = 10V, I _C = 1 mA
Collector to emitter saturation voltage	V _{CE(sat)}	—	1.37	1.8	V	I _C = 40 A, V _{GE} = 15V ^{Note2}
	V _{CE(sat)}	—	1.7	—	V	I _C = 80 A, V _{GE} = 15V ^{Note2}
Input capacitance	C _{ies}	—	2780	—	pF	V _{CE} = 25 V V _{GE} = 0 V f = 1 MHz
Output capacitance	C _{oes}	—	100	—	pF	
Reverse transfer capacitance	C _{res}	—	43	—	pF	
Total gate charge	Q _g	—	74	—	nC	V _{GE} = 15 V V _{CC} = 300 V I _C = 40 A
Gate to emitter charge	Q _{ge}	—	24	—	nC	
Gate to collector charge	Q _{gc}	—	26	—	nC	
Switching time	t _{d(on)}	—	53	—	ns	I _C = 30 A, V _{CE} = 400 V, V _{GE} = 15 V R _g = 5 Ω ^{Note3} , Inductive load
	t _r	—	77	—	ns	
	t _{d(off)}	—	90	—	ns	
	t _f	—	85	—	ns	

Notes: 2. Pulse test

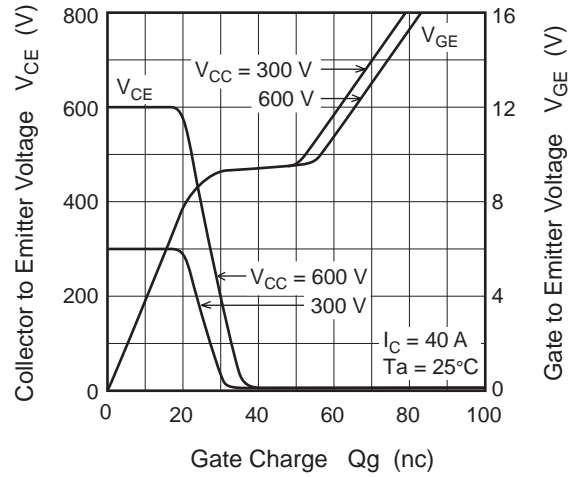
Main Characteristics



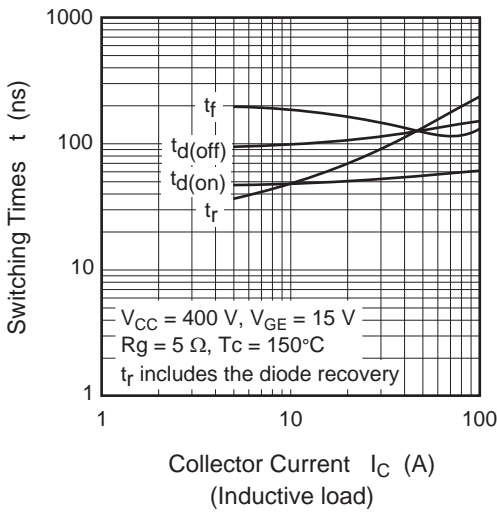
Typical Capacitance vs. Collector to Emitter Voltage



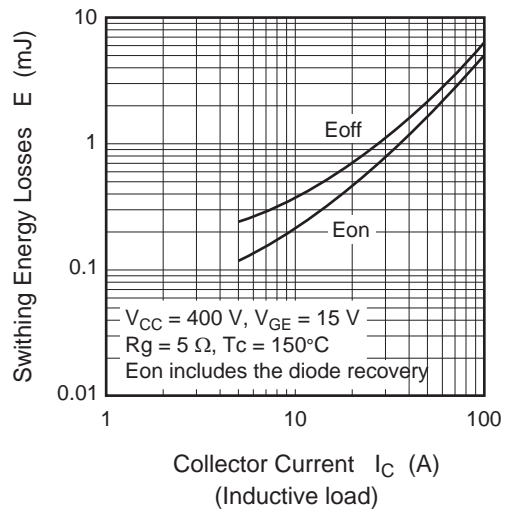
Dynamic Input Characteristics (Typical)



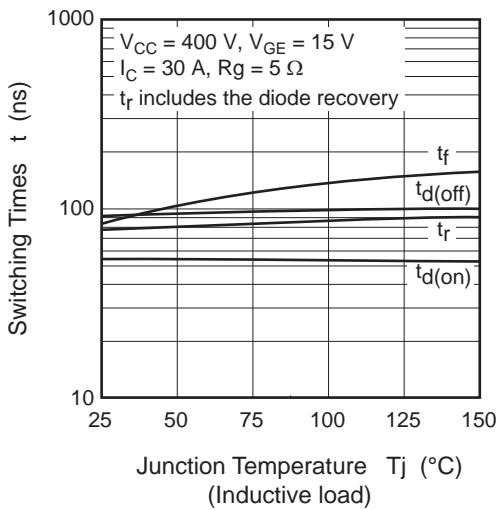
Switching Characteristics (Typical) (1)



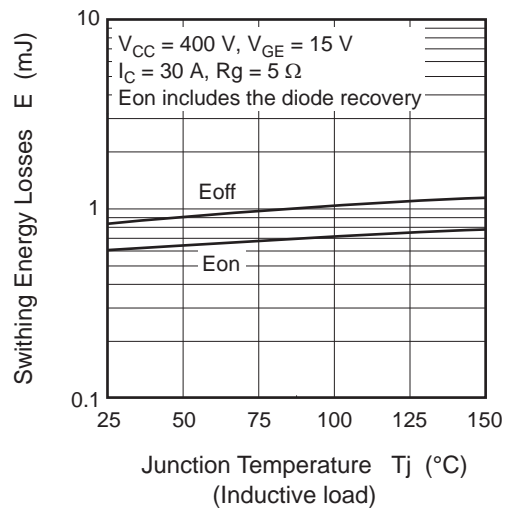
Switching Characteristics (Typical) (2)

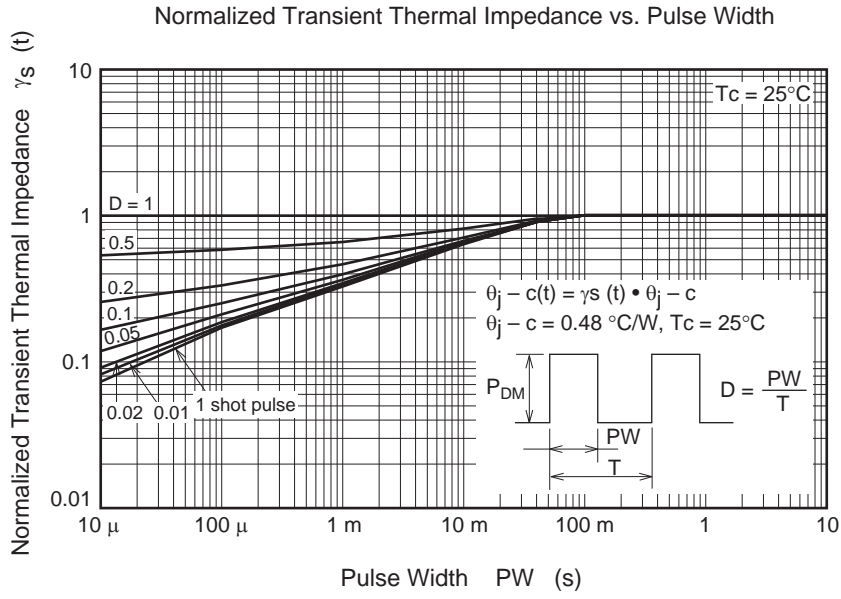


Switching Characteristics (Typical) (3)

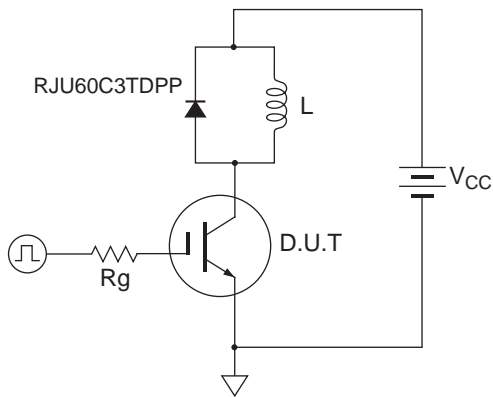


Switching Characteristics (Typical) (4)

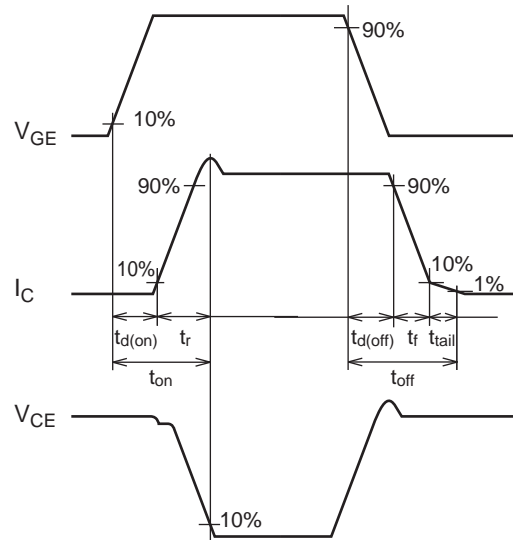




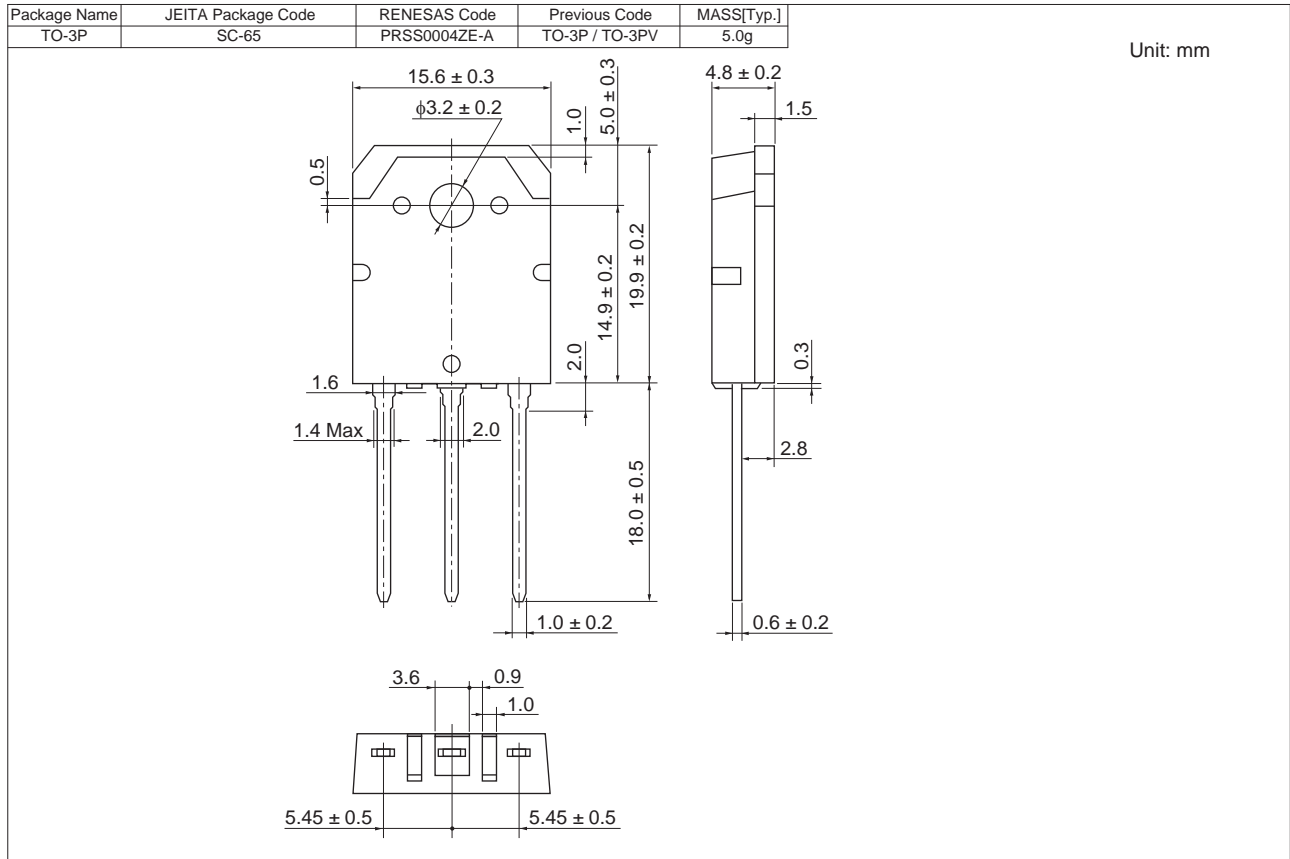
Switching Time Test Circuit



Waveform



Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJP60F5DPK-00#T0	360 pcs	Box (Tube)

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